03500.010530.5 PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE.

| In re Application of: |) | |
|--------------------------------|-----|---------------------------------|
| | : | Examiner: George R. Fourson, II |
| Kiyofumi SAKAGUCHI, et al. |) | |
| | : | Group Art Unit: 2823 |
| Appln. No.: 10/085,046 |) | |
| | : | Confirmation No.: 7805 |
| Filed: March 1, 2002 |) | |
| | | |
| For: PROCESS FOR PRODUCTION OF |) | |
| SEMICONDUCTOR SUBSTRATE | - 1 | November 7, 2006 |

Mail Stop Amendment

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

FIFTH INFORMATION DISCLOSURE STATEMENT

Sir:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §§ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the enclosed Form PTO-1449. Copies of the listed documents, other than U.S. patent documents, are enclosed.

REMARKS

An English-language Abstract for JP-A 60-196955 was obtained from a commercial database and is also enclosed.

FORMAL MATTERS

No fee is believed due; however, any fee required in connection with this paper should be charged to Deposit Account No. 06-1205.

CONCLUSION

It is respectfully requested that the above information be considered by the Examiner and that a copy of the enclosed Form PTO-1449 be returned indicating that such information has been considered.

Applicants' undersigned attorney may be reached in our Washington, D.C. office by telephone at (202) 530-1010. All correspondence should continue to be directed to our address given below.

Respectfully submitted.

Attorney for Applicants

Daniel S. Glueck Registration No. 37,838

FITZPATRICK, CELLA, HARPER & SCINTO 30 Rockefeller Plaza

New York, New York 10112-3800 Facsimile: (212) 218-2200

| LIST OF REFERENCES CITED BY APPLICANT(S) | | Kiyofumi SAKAGUCHI, et al. | | | | | | | |
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| CAMINER Initial | reference considered, whether or a | not citation is in conform | rance with MPEP 609; Draw line through | citation If not in | conformance a | and not considered. Include conv | | | |
| his form with next | communication to applicant. | | | | | Sheet 1 of 2 | | | |

ATTY DOCKET NO 03500.010530.5

FORM PTO 1449 (modified)

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U.S. DEPARTMENT OF COMMERCE

APPLICATION NO 10/085,046

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| LIST OF | REFERENCES CITED BY APPLIC | ANT(S) | Kiyofumi S | AKAGUCH | ll, et al. | | |
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